

MiniSKiiP® 3

SKiiP 38AC12T4V1

Features

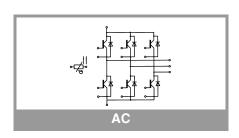
- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532

Typical Applications*

- Inverter up to 41 kVA
- Typical motor power 22 kW

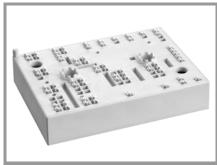
Remarks

- Max. case temperature limited to T_C=125°C
- Product reliability results valid for T_j≤150°C (recommended T_{j,op}=-40...+150°C)
- For short circuit: Soft R_{Goff} recommended
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.



Absolute	Maximum Ratings	s		
Symbol	Conditions		Values	Unit
Inverter -	IGBT		•	•
V _{CES}	T _j = 25 °C		1200	V
Ic	λ_{paste} =0.8 W/(mK) T _j = 175 °C	T _s = 25 °C	115	А
		T _s = 70 °C	93	Α
I _C	λ_{paste} =2.5 W/(mK) T _j = 175 °C	T _s = 25 °C	140	Α
		T _s = 70 °C	114	Α
I _{Cnom}			100	Α
I _{CRM}	$I_{CRM} = 3 \times I_{Cnom}$		300	Α
V _{GES}			-20 20	V
t _{psc}	$V_{CC} = 800 \text{ V}$ $V_{GE} \le 15 \text{ V}$ $V_{CES} \le 1200 \text{ V}$	T _j = 150 °C	10	μs
Tj			-40 175	°C
Inverse -	Diode			
	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	100	Α
	T _j = 175 °C	T _s = 70 °C	79	Α
l _F	λ_{paste} =2.5 W/(mK) T _j = 175 °C	T _s = 25 °C	116	Α
		T _s = 70 °C	93	Α
I _{Fnom}			100	Α
I _{FRM}	$I_{FRM} = 3 \times I_{Fnom}$		300	Α
I _{FSM}	10 ms, sin 180°, T _j = 150 °C		550	Α
Tj			-40 175	°C
Module				•
I _{t(RMS)}	T _{terminal} = 80 °C, 20 A per spring		160	Α
T _{stg}			-40 125	°C
V _{isol}	AC sinus 50 Hz, t = 1 min		2500	V

Characteristics								
Symbol	Conditions		min.	typ.	max.	Unit		
Inverter - IGBT								
V _{CE(sat)}	I _C = 100 A	T _j = 25 °C		1.80	2.05	V		
V _{GE} = 15 V chiplevel	T _j = 150 °C		2.20	2.40	V			
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V		
		T _j = 150 °C		0.70	0.80	V		
	V _{GE} = 15 V	T _j = 25 °C		10	12	mΩ		
	chiplevel	T _j = 150 °C		15	16	mΩ		
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 4 \text{ m/s}$	Ā	5	5.8	6.5	V		
I _{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 12$	00 V, T _j = 25 °C		0.1	0.3	mA		
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		6.15		nF		
C _{oes}		f = 1 MHz		0.41		nF		
C _{res}		f = 1 MHz		0.35		nF		
Q_{G}	- 8 V+ 15 V			565		nC		
R _{Gint}	T _j = 25 °C			7.5		Ω		
t _{d(on)}	$V_{CC} = 600 \text{ V}$	T _j = 150 °C		160		ns		
t _r	$\begin{split} I_C &= 100 \text{ A} \\ R_{G \text{ on}} &= 1 \Omega \\ R_{G \text{ off}} &= 1 \Omega \\ \text{di/dt}_{\text{on}} &= 2080 \text{ A/}\mu\text{s} \\ \text{di/dt}_{\text{off}} &= 1240 \text{ A/}\mu\text{s} \end{split}$	T _j = 150 °C		45		ns		
E _{on}		T _j = 150 °C		13.7		mJ		
t _{d(off)}		T _j = 150 °C		395		ns		
t _f				73		ns		
E _{off}	V _{GE} = +15/-15 V	T _j = 150 °C		9.7		mJ		
R _{th(j-s)}	per IGBT, λ _{paste} =0.8 W/(mK)			0.48		K/W		
$R_{th(j-s)}$	per IGBT, λ _{paste} =2.5 W/(mK)			0.34		K/W		



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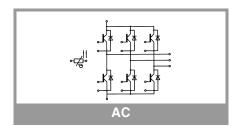
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Characteristics									
Symbol	Conditions		min.	typ.	max.	Unit			
Inverse - Diode									
$V_F = V_{EC}$	I _F = 100 A	T _j = 25 °C		2.20	2.52	V			
V _{GE} = 0 V chiplevel	T _j = 150 °C		2.15	2.47	V				
V_{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V			
		T _j = 150 °C		0.90	1.10	V			
r _F	chiplevel	T _j = 25 °C		9.0	10	$m\Omega$			
		T _j = 150 °C		13	14	$m\Omega$			
I _{RRM}	di/dt _{off} = 2680 A/μs +15/-15	T _j = 150 °C		112		Α			
Q _{rr}		T _j = 150 °C		16		μC			
E _{rr}		T _j = 150 °C		6.5		mJ			
R _{th(j-s)}	per Diode, λ _{paste} =0.8 W/(mK)			0.66		K/W			
R _{th(j-s)}	per Diode, λ _{paste} =2.5 W/(mK)			0.52		K/W			
Module									
L _{CE}						nΗ			
Ms	to heat sink		2		2.5	Nm			
W				82		g			
Temperat	ture Sensor								
R ₁₀₀	T _r =100°C (R ₂₅ =1000Ω)			1670 ± 3%		Ω			
R(T)	R(T)=1000 Ω [1+A(T-25°C)+B(T-25°C) ²], A = 7.635*10 ⁻³ °C ⁻¹ , B = 1.731*10 ⁻⁵ °C ⁻²								



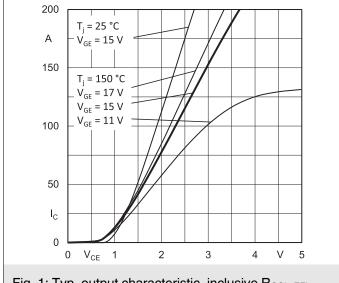


Fig. 1: Typ. output characteristic, inclusive $R_{\text{CC}'\text{+ EE'}}$

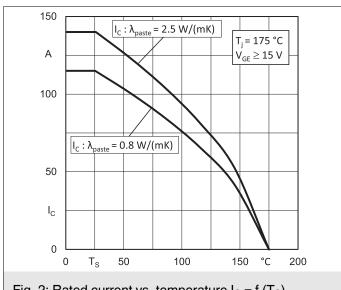


Fig. 2: Rated current vs. temperature $I_C = f(T_S)$

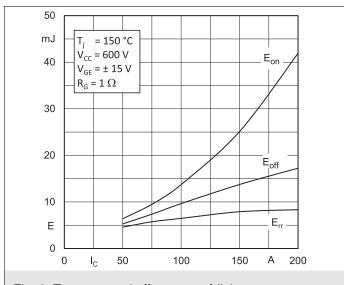


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

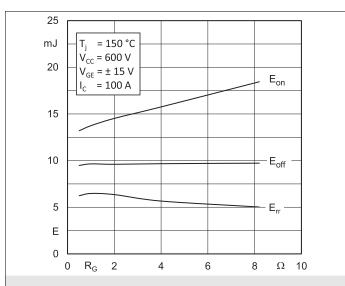


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

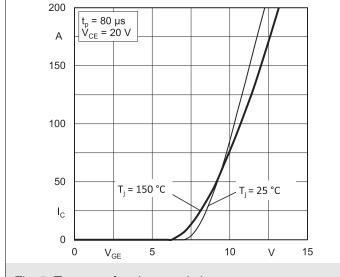


Fig. 5: Typ. transfer characteristic

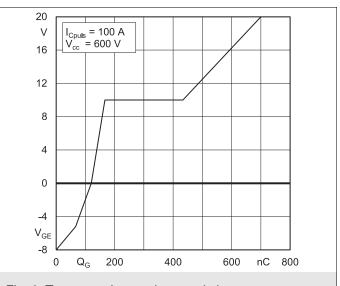


Fig. 6: Typ. gate charge characteristic

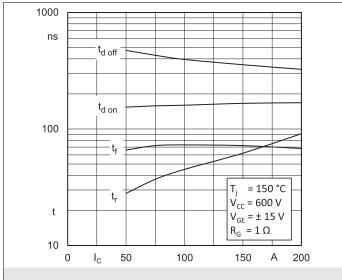


Fig. 7: Typ. switching times vs. I_C

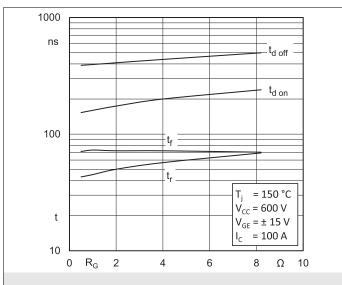


Fig. 8: Typ. switching times vs. gate resistor R_{G}

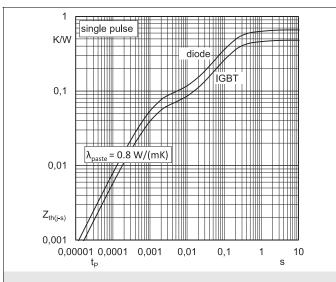


Fig. 9: Transient thermal impedance of IGBT and Diode

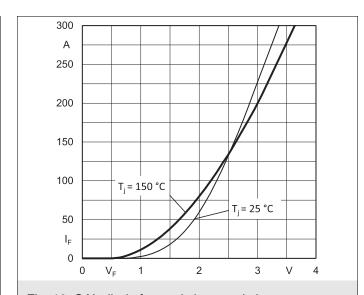


Fig. 10: CAL diode forward characteristic

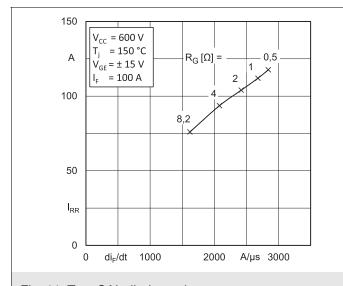


Fig. 11: Typ. CAL diode peak reverse recovery current

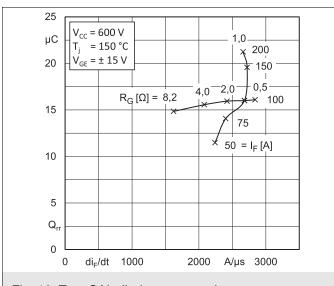
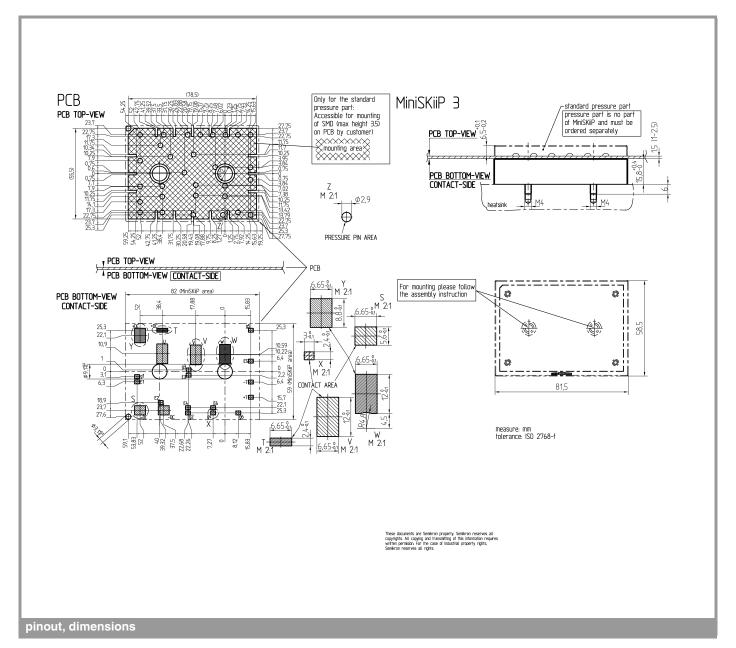
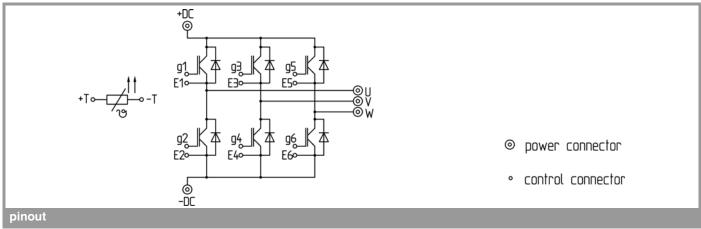


Fig. 12: Typ. CAL diode recovery charge





This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

*IMPORTANT INFORMATION AND WARNINGS

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FD400R12KE3 FD400R33KF2C-K FD401R17KF6C_B2 FD-DF80R12W1H3_B52 FF100R12KS4 FF1200R17KE3_B2 FF150R12KE3G

FF200R06KE3 FF200R06YE3 FF200R12KT3 FF200R12KT3_E FF200R12KT4 FF200R17KE3 FF300R06KE3_B2 FF300R12KE4_E

FF300R12KS4HOSA1 FF300R12ME4_B11 FF300R12MS4 FF300R17ME4 FF450R12ME4P FF450R17IE4 FF600R12IE4V

FF600R12IP4V FF800R17KP4_B2 FF900R12IE4V MIXA30W1200TED MIXA450PF1200TSF FP06R12W1T4_B3 FP100R07N3E4

FP100R07N3E4_B11 FP10R06W1E3_B11 FP10R12W1T4_B11 FP10R12YT3 FP10R12YT3_B4 FP150R07N3E4 FP15R12KT3

FP15R12W2T4